

Excellent Integrated System Limited

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>V60M120C-M3/4W</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of V60M120C-M3/4W - DIODE SCHOTTKY 120V TO220

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



V60M120C-M3, V60M120CHM3

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.43 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 30 A				
V_{RRM}	120 V				
I _{FSM}	300 A				
V_F at $I_F = 30 \text{ A } (T_A = 125 \text{ °C})$	0.69 V				
T _J max.	175 °C				
Package	TO-220AB				

Dual common cathode

Diode variations

FEATURES

Trench MOS Schottky technology

• Low forward voltage drop, low power losses

COMPLIANT

• High efficiency operation

• Solder dip 275 °C max. 10 s, per JESD 22-B106

HALOGEN FREE

• AEC-Q101 qualified

 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix

meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60M120C	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	120	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	60	A	
	per diode		30		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	300	,,	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +175	°C	

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ELECTRICAL CHARACTERISTICS							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.51	-	V	
	I _F = 15 A			0.68	-		
	$I_F = 30 \text{ A}$			0.86	0.97		
	I _F = 5 A	T _A = 125 °C		0.43	-		
	I _F = 15 A			0.58	-		
	$I_F = 30 \text{ A}$			0.69	0.77		
Reverse current per diode	V _R = 90 V	T _A = 25 °C	I _R ⁽²⁾	75	-	μΑ	
		T _A = 125 °C		6.4	-	mA	
	Vp = 120 V	T _A = 25 °C		-	500	μΑ	
		T _A = 125 °C		10	35	mA	

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL V60M120C		UNIT	
Typical thermal resistance (1)	per diode	R _{θJA} (2)	1.0	°C/W	
	per device		0.7		
	per device		52		

Notes

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient $dP_D/dT_J < 1/R_{\theta,JA}$

(2) Free air, without heatsink

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V60M120C-M3/4W	1.89	4W	50/tube	Tube		
TO-220AB	V60M120CHM3/4W (1)	1.89	4W	50/tube	Tube		

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

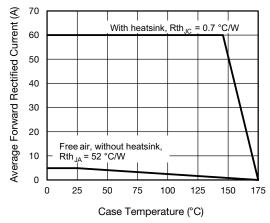


Fig. 1 - Maximum Forward Current Derating Curve (D = Duty Cycle = 0.5)

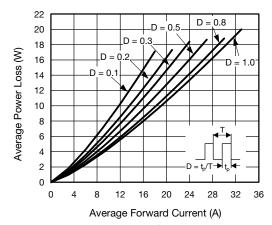


Fig. 2 - Forward Power Loss Characteristics Per Diode

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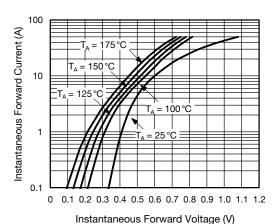


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

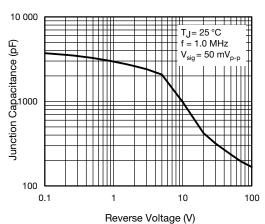
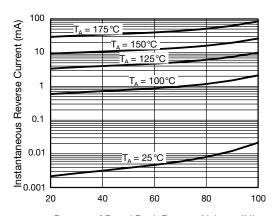


Fig. 5 - Typical Junction Capacitance Per Diode



Percent of Rated Peak Reverse Voltage (%)
Fig. 4 - Typical Reverse Characteristics Per Diode

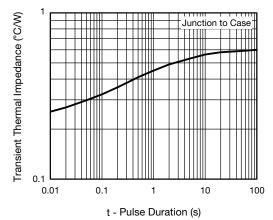
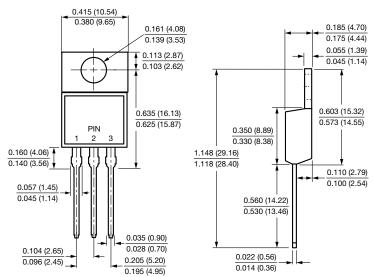


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



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